

Article

Study of the properties of CdS:Al ($R = [Al]/[Cd] = 0.30, 0.40, 0.50$) thin films grown by the CBD method in an ammonia-free system

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Supporting information

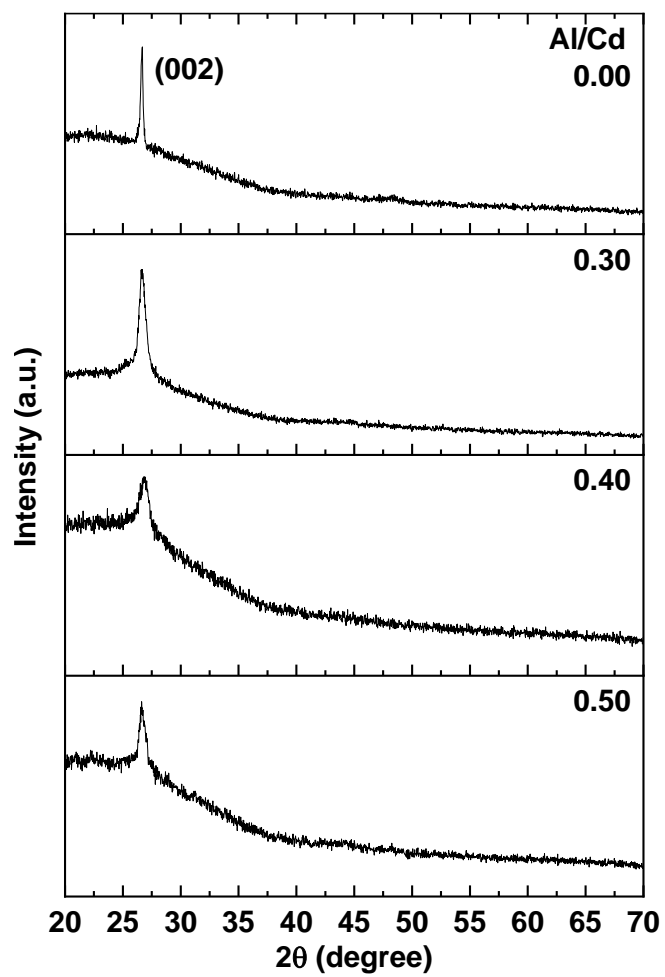


Figure S1. XRD pattern of thin films grown at different [Al]/[Cd] ratios. From Ref. [1].

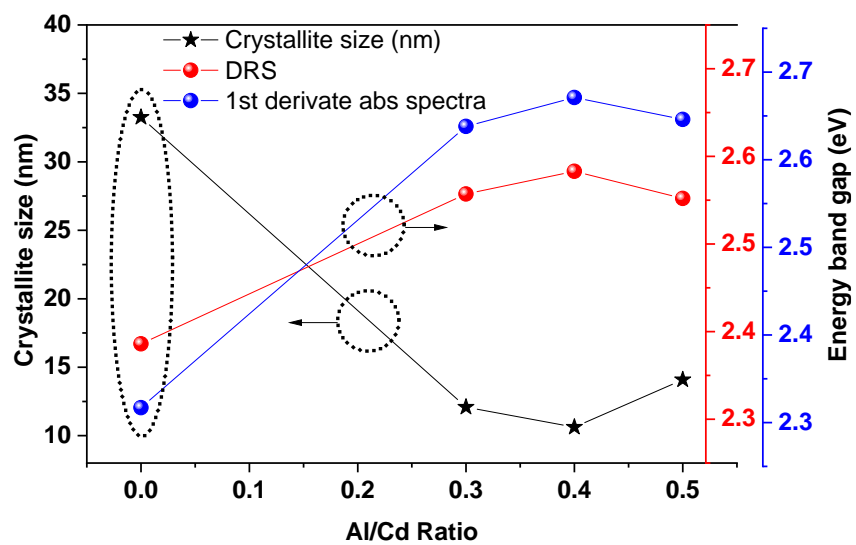


Figure S2 Crystallite size and energy gap versus [A]/[Cd] ratio for the thin films. From Ref. [1].